# NSN 5961-00-348-5788

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# Inclosure Material:

Metal

**Overall Length:** 

Between 0.345 inches and 0.400 inches

# **Overall Diameter:**

0.400 inches

# **Mounting Facility Quantity:**

1

### Internal Configuration:

Junction contact

### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

### **Overall Width Across Flats:**

Between 0.427 inches and 0.437 inches

### Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 70.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 0.50 amperes source cutoff current and 5.00 amperes source cutoff current

# Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

3 tab, solder lug

### Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

## Fiig:

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